



DMN61D9UT

#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) max	I <sub>D</sub> max T <sub>A</sub> = +25°C
60V	2Ω @ V <sub>GS</sub> = 5.0V	350mA
007	2.5Ω @ V <sub>GS</sub> = 2.5V	330IIIA

#### Description

This MOSFET is designed to minimize the on-state resistance (RDs(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### Applications

- Motor Control
- Power Management Functions

#### Features

- Low On-Resistance: RDS(ON)
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact</u> <u>us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

**Mechanical Data** 

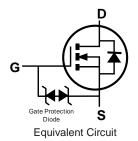
- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208(e3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)

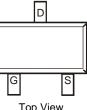




SOT523

Top View





Pin Out Configuration

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN61D9UT-7	SOT523	3000/Tape & Reel
DMN61D9UT-13	SOT523	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

. See https://www.diodes.com/quality/lead-free/ for more information about Diodes incorporated s definitions of Halogen- and Antimony-free, Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

		1	
	9D2	YM	
'			
	2015		2

9D2 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key												
Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	С		Н	I	J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		Vdss	60	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 6) $V_{GS} = 5.0V$ Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		lD	350 280	mA
Maximum Continuous Body Diode Forward Curren	nt (Note 6)	ls	350	mA
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)	IDM	1.1	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	260	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	491	°C/W
Total Power Dissipation (Note 6)		PD	370	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	342	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

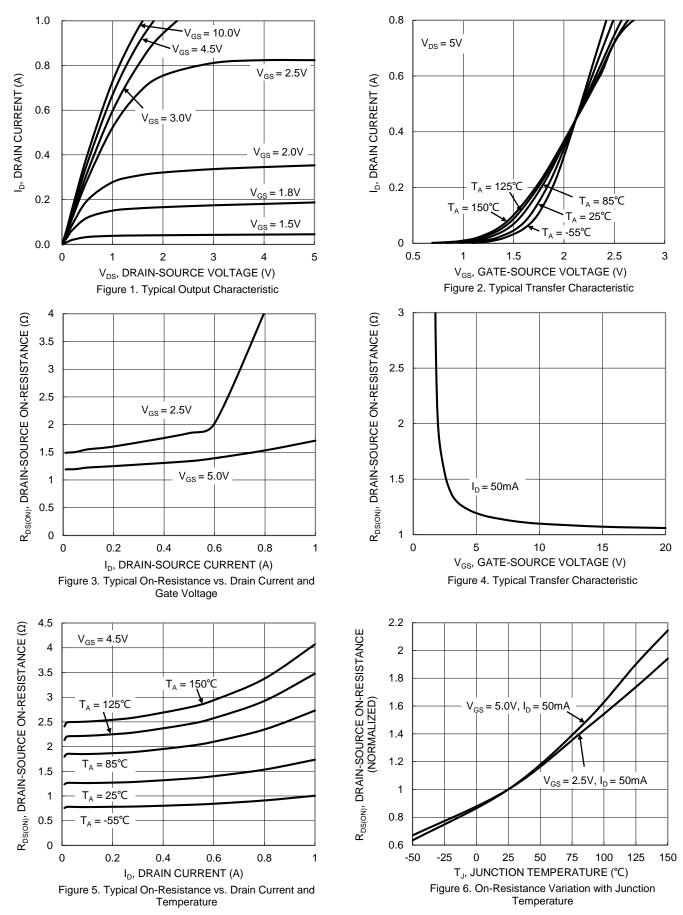
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						·
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	-	_	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	lgss			±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5		1.0	V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 250µA
			1.2	2.0		VGS = 5.0V, ID = 0.05A
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		1.6	2.5	Ω	$V_{GS} = 2.5 V, I_D = 0.05 A$
			2.5	3.5		VGS = 1.8V, ID = 0.05A
Forward Transconductance	Y <sub>fs</sub>	200	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	Vsd	_	0.75	1.4	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 115mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		28.5		pF	
Output Capacitance	Coss		3.9	_	pF	$V_{DS} = 30V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.5		pF	1 = 1.00012
Gate Resistance	Rg	_	65	_	Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	Qg	_	0.4	-	nC	
Gate-Source Charge	Q <sub>gs</sub>		0.1		nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, ID = 250mA
Gate-Drain Charge	Qgd	_	0.1	_	nC	ID = 250MA
Turn-On Delay Time	tD(ON)	_	2.1	—	ns	
Turn-On Rise Time	tR	—	1.8		ns	V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V,
Turn-Off Delay Time	tD(OFF)		14.4	—	ns	$R_{G} = 25\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	tF		8.4	_	ns	

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

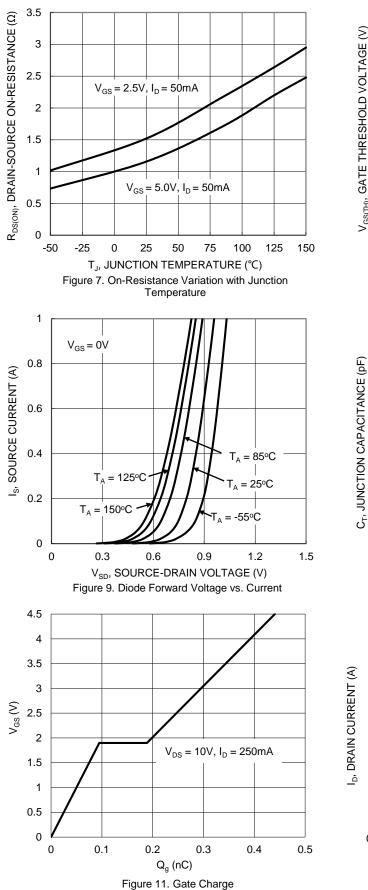


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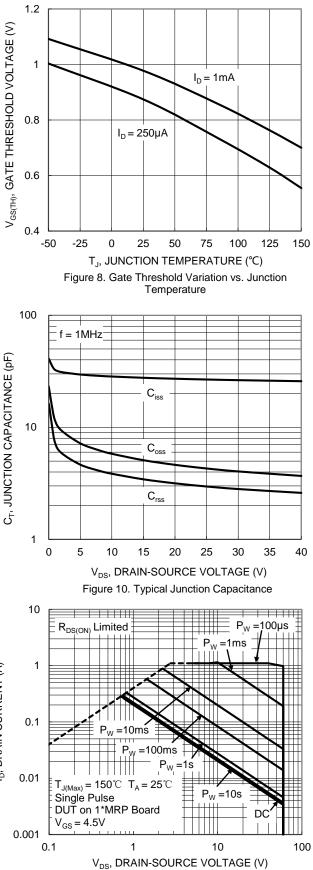
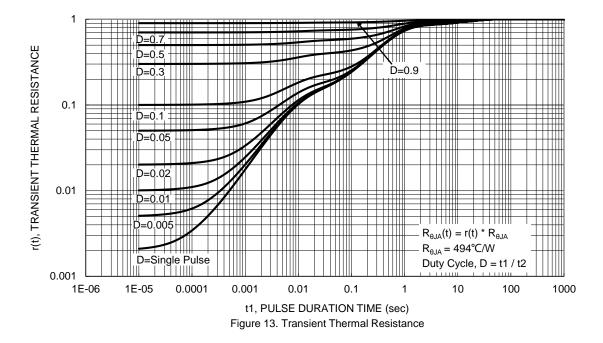


Figure 12. SOA, Safe Operation Area

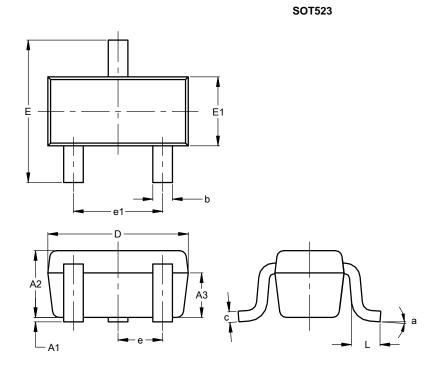






### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

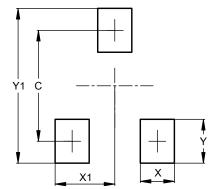


SOT523								
Dim	Min Max Typ							
A1	0.00	0.10	0.05					
A2	0.60	0.80	0.75					
A3	0.45	0.65	0.50					
b	0.15	0.30	0.22					
c	0.10	0.10 0.20 0.1						
D	1.50	1.70	1.60					
ш	1.45	1.75	1.60					
E1	0.75	0.80						
е		0.50 BS	С					
e1	0.90	.90 1.10 1.00						
L	0.20	0.40	0.33					
а	<b>a</b> 0° 8°							
Α	All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT523



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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